

## General Description

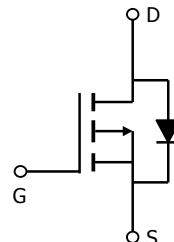
The AOD413A uses advanced technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. With the excellent thermal resistance of the DPAK package, this device is well suited for high current load applications.



1.G    2.D    3.S  
TO-252(DPAK) top view

## Features

- $V_{DS(V)} = -40V$
- $I_D = -12A$  ( $V_{GS} = 10V$ )
- $R_{DS(ON)} < 44m\Omega$  ( $V_{GS} = -10V$ )
- $R_{DS(ON)} < 66m\Omega$  ( $V_{GS} = -4.5V$ )



## Absolute Maximum Ratings $T_A=25^\circ C$ unless otherwise noted

Parameter	Symbol	Maximum	Units
Drain-Source Voltage	$V_{DS}$	-40	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Continuous Drain Current <sup>B,H</sup>	$I_D$	-12	A
$T_C=100^\circ C$		-12	
Pulsed Drain Current <sup>C</sup>	$I_{DM}$	-30	
Avalanche Current <sup>C</sup>	$I_{AR}$	-20	
Repetitive avalanche energy $L=0.1mH$ <sup>C</sup>	$E_{AR}$	20	mJ
Power Dissipation <sup>B</sup>	$P_D$	50	W
$T_C=25^\circ C$		25	
Power Dissipation <sup>A</sup>	$P_{DSM}$	2.5	
$T_A=70^\circ C$		1.6	
Junction and Storage Temperature Range	$T_J, T_{STG}$	-55 to 175	°C

## Thermal Characteristics

Parameter	Symbol	Typ	Max	Units
Maximum Junction-to-Ambient <sup>A</sup>	$R_{\theta JA}$	16.7	25	°C/W
Steady-State		40	50	°C/W
Maximum Junction-to-Case <sup>D</sup>	$R_{\theta JC}$	2.5	3	°C/W

**Electrical Characteristics ( $T_J=25^\circ\text{C}$  unless otherwise noted)**

Symbol	Parameter	Conditions	Min	Typ	Max	Units
$\text{BV}_{\text{DSS}}$	Drain-Source Breakdown Voltage	$I_D = -250\mu\text{A}, V_{GS}=0\text{V}$	-40			V
$I_{\text{DSS}}$	Zero Gate Voltage Drain Current	$V_{DS} = -40\text{V}, V_{GS}=0\text{V}$ $T_J=55^\circ\text{C}$			-1 -5	$\mu\text{A}$
$I_{\text{GSS}}$	Gate-Body leakage current	$V_{DS}=0\text{V}, V_{GS}= \pm 20\text{V}$			$\pm 100$	nA
$V_{\text{GS(th)}}$	Gate Threshold Voltage	$V_{DS}=V_{GS}, I_D = -250\mu\text{A}$	-1.7	-2	-3	V
$I_{\text{D(ON)}}$	On state drain current	$V_{GS} = -10\text{V}, V_{DS} = -5\text{V}$	-30			A
$R_{\text{DS(ON)}}$	Static Drain-Source On-Resistance	$V_{GS} = -10\text{V}, I_D = -12\text{A}$		36	44	$\text{m}\Omega$
		$V_{GS} = -4.5\text{V}, I_D = -8\text{A}$		52	66	
$g_{\text{FS}}$	Forward Transconductance	$V_{DS} = -5\text{V}, I_D = -12\text{A}$		22		S
$V_{\text{SD}}$	Diode Forward Voltage	$I_S = -1\text{A}, V_{GS}=0\text{V}$		-0.76	-1	V
$I_S$	Maximum Body-Diode Continuous Current				-12	A
$C_{\text{iss}}$	Input Capacitance	$V_{GS}=0\text{V}, V_{DS} = -20\text{V}, f=1\text{MHz}$		900	1125	pF
$C_{\text{oss}}$	Output Capacitance			97		pF
$C_{\text{rss}}$	Reverse Transfer Capacitance			68		pF
$R_g$	Gate resistance	$V_{GS}=0\text{V}, V_{DS}=0\text{V}, f=1\text{MHz}$		14		$\Omega$
$Q_g(-10\text{V})$	Total Gate Charge	$V_{GS} = -10\text{V}, V_{DS} = -20\text{V}, I_D = -12\text{A}$		16.2	21	nC
$Q_g(-4.5\text{V})$	Total Gate Charge			7.2	9.4	nC
$Q_{\text{gs}}$	Gate Source Charge			3.8		nC
$Q_{\text{gd}}$	Gate Drain Charge			3.5		nC
$t_{\text{D(on)}}$	Turn-On DelayTime	$V_{GS} = -10\text{V}, V_{DS} = -20\text{V}, R_L = 1.6\Omega, R_{\text{GEN}} = 3\Omega$		6.2		ns
$t_r$	Turn-On Rise Time			8.4		ns
$t_{\text{D(off)}}$	Turn-Off DelayTime			44.8		ns
$t_f$	Turn-Off Fall Time			41.2		ns
$t_{\text{rr}}$	Body Diode Reverse Recovery Time	$I_F = -12\text{A}, dI/dt = 100\text{A}/\mu\text{s}$		21.2		ns
$Q_{\text{rr}}$	Body Diode Reverse Recovery Charge	$I_F = -12\text{A}, dI/dt = 100\text{A}/\mu\text{s}$		13.8		nC

A: The value of  $R_{\theta JA}$  is measured with the device in a still air environment with  $T_A = 25^\circ\text{C}$ . The power dissipation  $P_{\text{DSM}}$  and current rating  $I_{\text{DSM}}$  are based on  $T_{J(\text{MAX})}=150^\circ\text{C}$ , using  $t \leq 10\text{s}$  junction-to-ambient thermal resistance.

B. The power dissipation  $P_D$  is based on  $T_{J(\text{MAX})}=175^\circ\text{C}$ , using junction-to-case thermal resistance, and is more useful in setting the upper dissipation limit for cases where additional heatsinking is used.

C: Repetitive rating, pulse width limited by junction temperature  $T_{J(\text{MAX})}=175^\circ\text{C}$ .

D. The  $R_{\theta JA}$  is the sum of the thermal impedance from junction to case  $R_{\theta JC}$  and case to ambient.

E. The static characteristics in Figures 1 to 6 are obtained using  $<300\ \mu\text{s}$  pulses, duty cycle 0.5% max.

F. These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsink, assuming a maximum junction temperature of  $T_{J(\text{MAX})}=175^\circ\text{C}$ . The SOA curve provides a single pulse rating.

G. These tests are performed with the device mounted on 1 in<sup>2</sup> FR-4 board with 2oz. Copper, in a still air environment with  $T_A=25^\circ\text{C}$ .

H. The maximum current rating is limited by bond-wires.

### TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

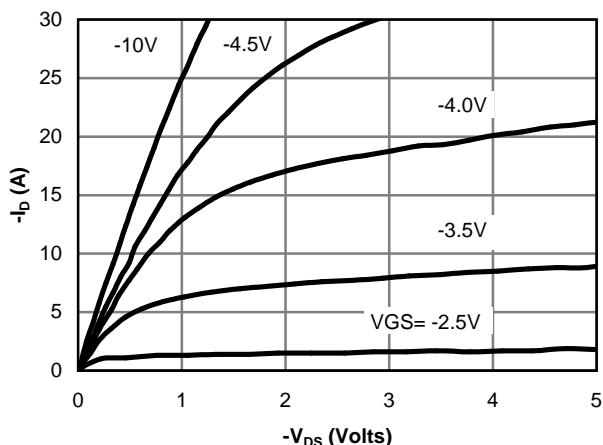


Figure 1: On-Region Characteristics

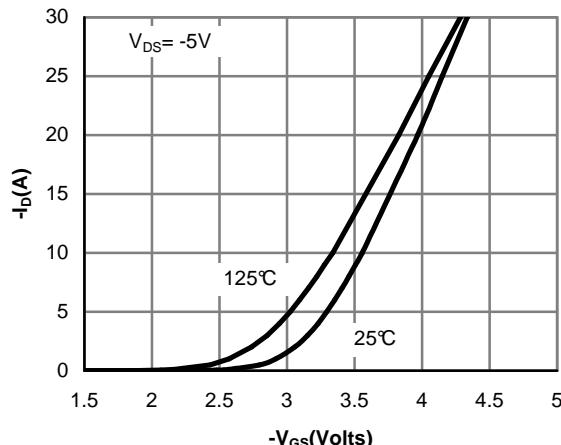


Figure 2: Transfer Characteristics

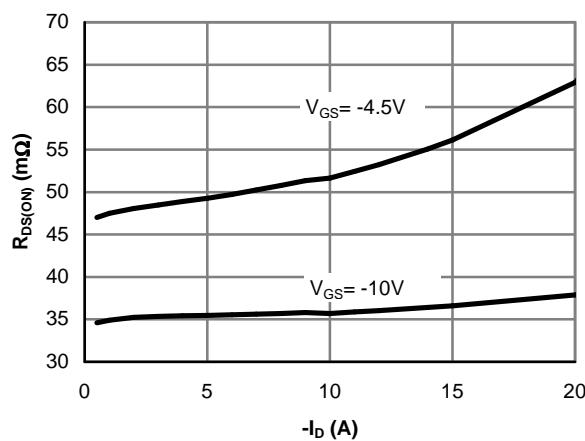


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

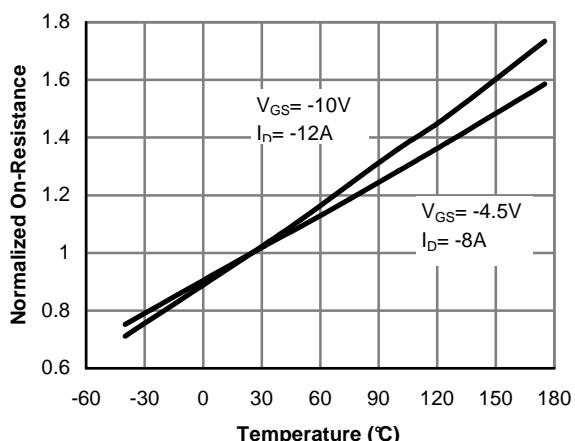


Figure 4: On-Resistance vs. Junction Temperature

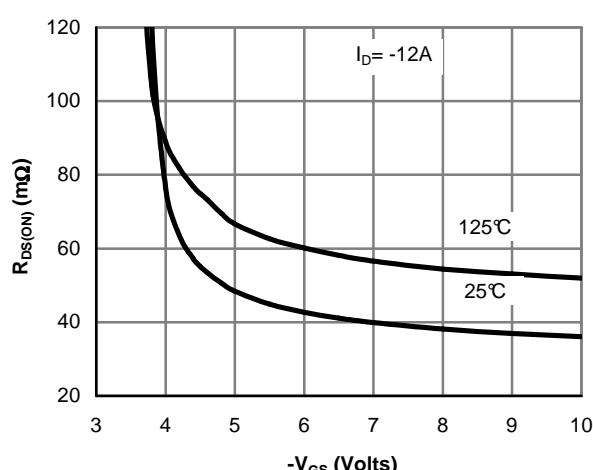


Figure 5: On-Resistance vs. Gate-Source Voltage

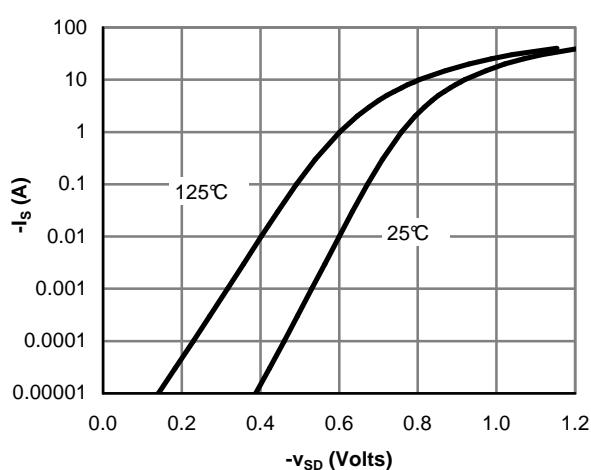
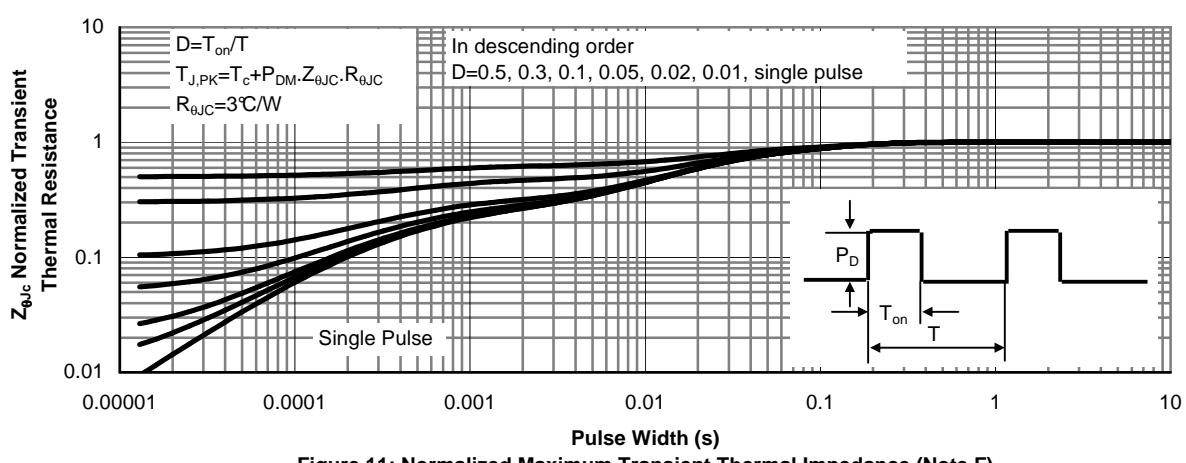
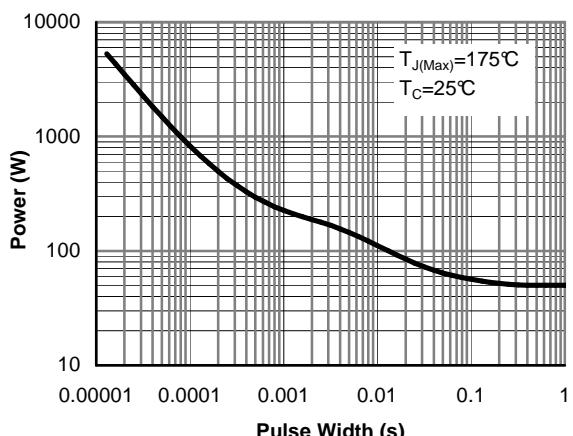
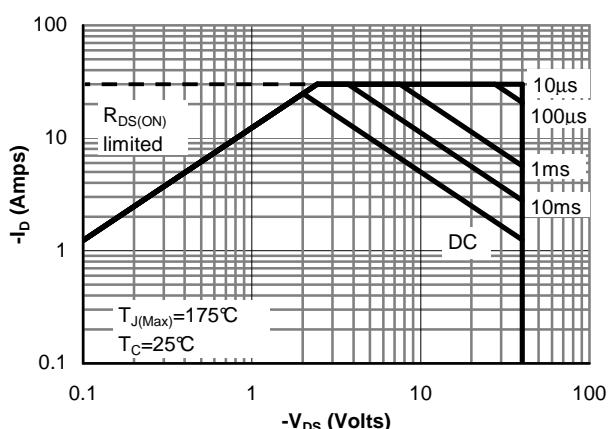
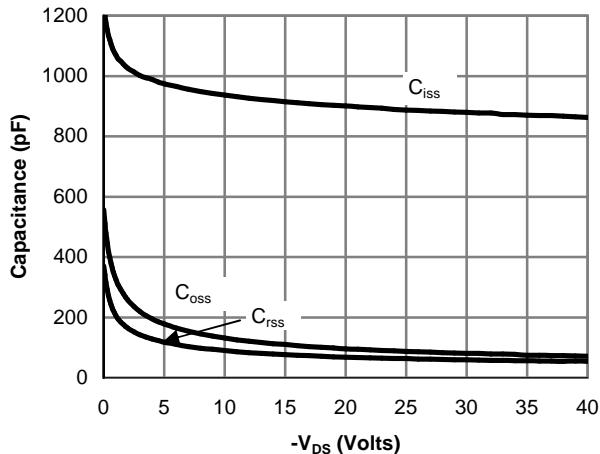
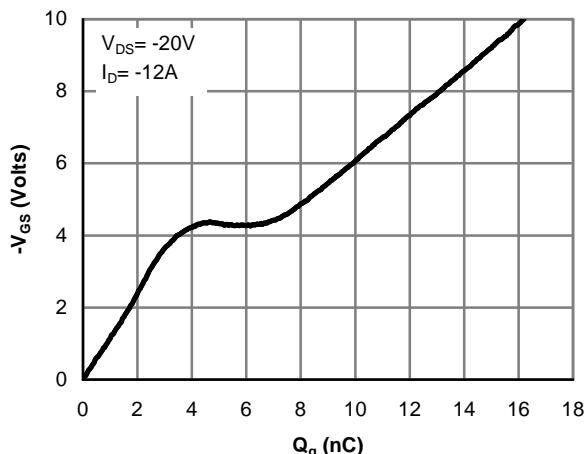


Figure 6: Body-Diode Characteristics

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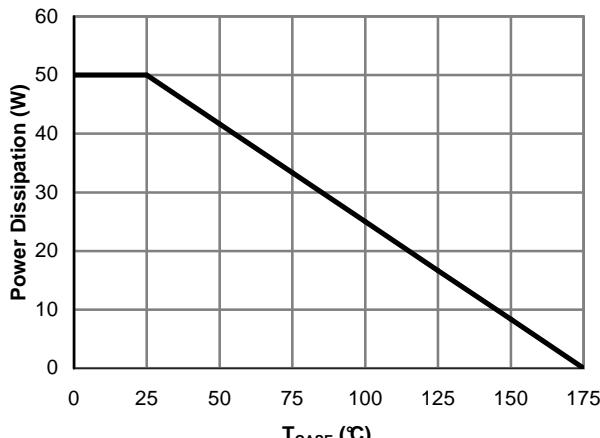


Figure 12: Power De-rating (Note B)

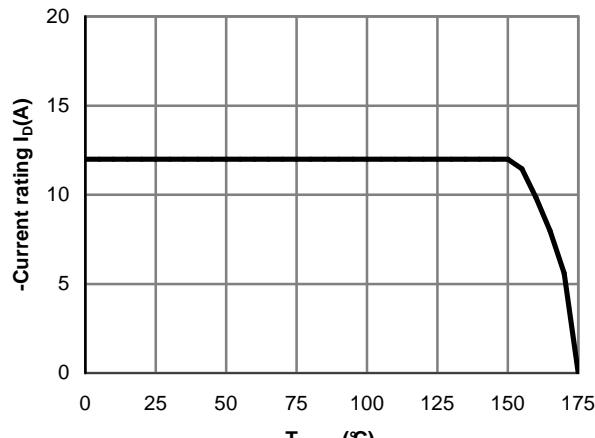


Figure 13: Current De-rating (Note B)

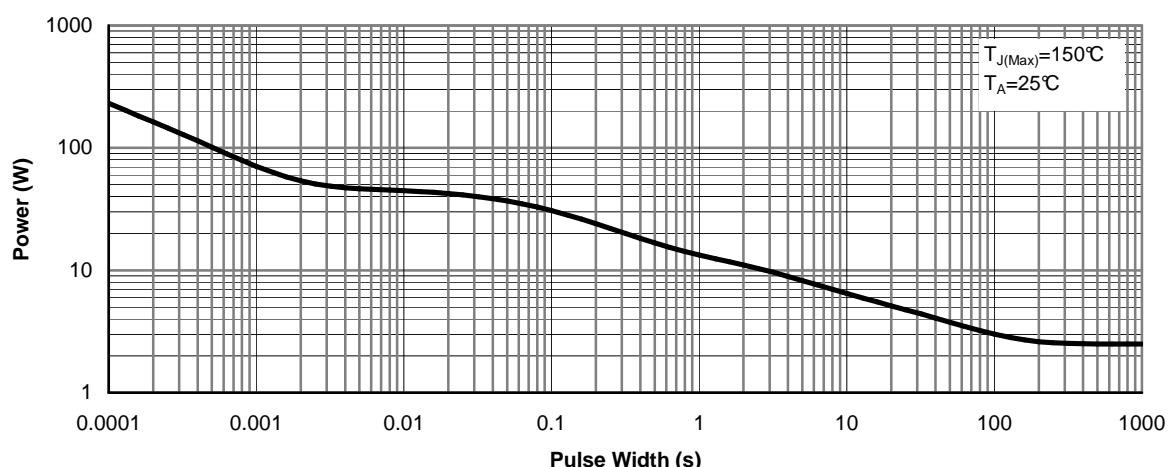


Figure 14: Single Pulse Power Rating Junction-to-Ambient (Note G)

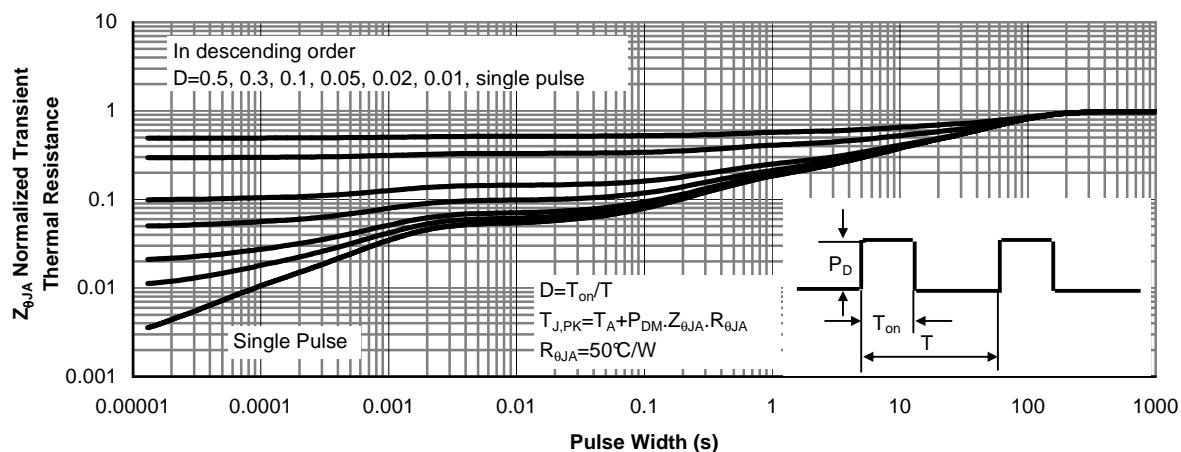
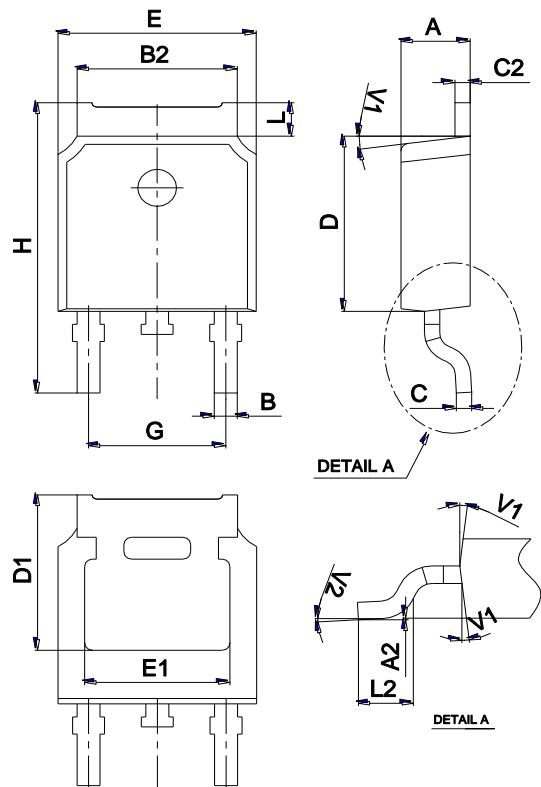


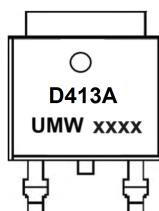
Figure 15: Normalized Maximum Transient Thermal Impedance (Note G)

### Package Mechanical Data TO-252



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.10		2.50	0.083		0.098
A2	0		0.10	0		0.004
B	0.66		0.86	0.026		0.034
B2	5.18		5.48	0.202		0.216
C	0.40		0.60	0.016		0.024
C2	0.44		0.58	0.017		0.023
D	5.90		6.30	0.232		0.248
D1	5.30REF			0.209REF		
E	6.40		6.80	0.252		0.268
E1	4.63			0.182		
G	4.47		4.67	0.176		0.184
H	9.50		10.70	0.374		0.421
L	1.09		1.21	0.043		0.048
L2	1.35		1.65	0.053		0.065
V1		7°			7°	
V2	0°		6°	0°		6°

### Marking



### Ordering information

Order code	Package	Baseqty	Deliverymode
UMW AOD413A	TO-252	2500	Tape and reel